

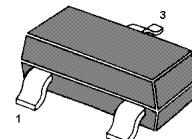
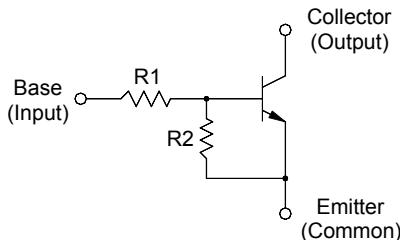
# MMBTRC107SS...MMBTRC109SS

## NPN Silicon Epitaxial Planar Transistor

for switching and interface circuit and drive circuit applications

### Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Resistor Values

Type	R1 (KΩ)	R2 (KΩ)
MMBTRC107SS	10	47
MMBTRC108SS	22	47
MMBTRC109SS	47	22

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Output Voltage	$V_o$	50	V
Input Voltage	$V_i$	30, -6	V
		40, -7	
		40, -15	
Output Current	$I_o$	100	mA
Total Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{Stg}$	- 55 to + 150	°C

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# MMBTRC107SS...MMBTRC109SS

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## Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_O = 5 \text{ V}$ , $I_O = 10 \text{ mA}$ MMBTRC107SS MMBTRC108SS MMBTRC109SS	$G_I$	80	-	-	-
		80	-	-	-
		70	-	-	-
Output Cutoff Current at $V_O = 50 \text{ V}$	$I_{O(OFF)}$	-	-	500	nA
Input Current at $V_I = 5 \text{ V}$ MMBTRC107SS MMBTRC108SS MMBTRC109SS	$I_I$	-	-	0.88	mA
		-	-	0.36	
		-	-	0.16	
Output Voltage at $I_O = 10 \text{ mA}$ , $I_I = 0.5 \text{ mA}$	$V_{O(ON)}$	-	-	0.3	V
Input Voltage (ON) at $V_O = 0.2 \text{ V}$ , $I_O = 5 \text{ mA}$ MMBTRC107SS MMBTRC108SS MMBTRC109SS	$V_{I(ON)}$	-	-	1.8	V
		-	-	2.6	
		-	-	5.8	
Input Voltage (OFF) at $V_O = 5 \text{ V}$ , $I_O = 0.1 \text{ mA}$ MMBTRC107SS MMBTRC108SS MMBTRC109SS	$V_{I(OFF)}$	0.5	-	-	V
		0.6	-	-	
		1.5	-	-	
Transition Frequency at $V_O = 10 \text{ V}$ , $I_O = 5 \text{ mA}$	$f_T$ <sup>1)</sup>	-	200	-	MHz

<sup>1)</sup> Characteristic of transistor only.

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